

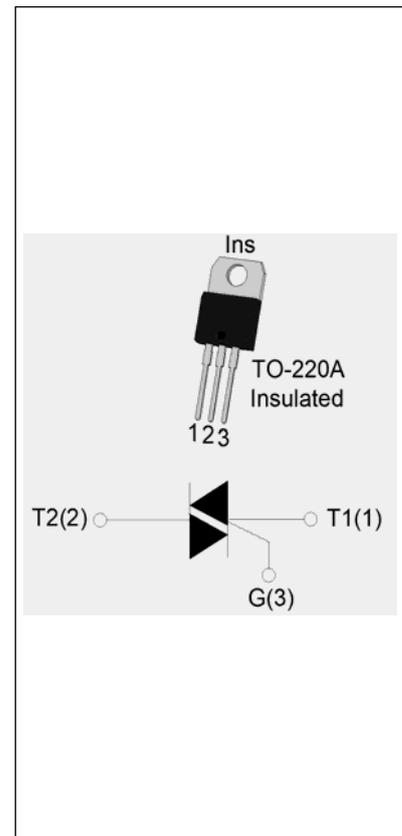


## DESCRIPTION:

The T1220H-6A triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. Compared to traditional triacs, T1220H-6A provides a very high switching capability up to junction temperatures of 150°C. By using an internal ceramic pad, T1220H-6A provides a rated insulation voltage of 2500 VRMS, complying with UL standards (File ref: E252906). Package TO-220A is RoHS compliant.

## MAIN FEATURES

| Symbol            | Value    | Unit |
|-------------------|----------|------|
| $I_{T(RMS)}$      | 12       | A    |
| $V_{DRM}/V_{RRM}$ | 600      | V    |
| $I_{GT} / /$      | 20/20/20 | mA   |



## ABSOLUTE MAXIMUM RATINGS

|  |              |         |                        |
|--|--------------|---------|------------------------|
| Storage junction temperature range   | $T_{stg}$    | -40-150 |                        |
| Operating junction temperature range   | $T_j$        | -40-150 |                        |
| Repetitive peak off-state voltage ( $T_j=25^\circ\text{C}$ )   | $V_{DRM}$    | 600     | V                      |
| Repetitive peak reverse voltage ( $T_j=25^\circ\text{C}$ )   | $V_{RRM}$    | 600     | V                      |
| RMS on-state current ( $T_c = 114^\circ\text{C}$ )   | $I_{T(RMS)}$ | 12      | A                      |
| Non repetitive surge peak on-state current (full cycle, $t_p=20\text{ms}$ , $T_j=25^\circ\text{C}$ )             | $I_{TSM}$    | 120     | A                      |
| Non repetitive surge peak on-state current (full cycle, $t_p=16.6\text{ms}$ , $T_j=25^\circ\text{C}$ )           |              | 132     |                        |
| $I^2t$ value for fusing ( $t_p=10\text{ms}$ , $T_j=25^\circ\text{C}$ )   | $I^2t$       | 72      | $\text{A}^2\text{s}$   |
| Critical rate of rise of on-state current ( $I_G=2 \times I_{GT}$ , $f=100\text{Hz}$ , $T_j=150^\circ\text{C}$ ) | $di/dt$      | 100     | $\text{A}/\mu\text{s}$ |
| Peak gate current ( $t_p=20\mu\text{s}$ , $T_j=150^\circ\text{C}$ )  | $I_{GM}$     | 4       | A                      |



|  |             |     |    |
|--|-------------|-----|----|
| Average gate power dissipation ( $T_j=150$ )                         | $P_{G(AV)}$ | 1   | W  |
| Peak gate power  | $P_{GM}$    | 10  | W  |
| Peak pulse voltage<br>( $T_j=25$ ; non-repetitive, off-state; FIG.7) | $V_{pp}$    | 4.5 | kV |

### ELECTRICAL CHARACTERISTICS ( $T_j=25$ unless otherwise specified)

|                      |  |     |      |     |            |
|----------------------|--|-----|------|-----|------------|
| $I_{GT}$             | $V_D=12V R_L=33$                               | - - | MAX. | 20  | mA         |
| $V_{GT}$             |  | - - | MAX. | 1   | V          |
| $V_{GD}$             | $V_D=V_{DRM} T_j=150$<br>$R_L=3.3K$            | - - | MIN. | 0.2 | V          |
| $I_L$                | $I_G=1.2I_{GT}$                                | -   | MAX. | 25  | mA         |
|                      |  |     |      | 55  |            |
| $I_H$                | $I_T=500mA$                                    |     | MAX. | 25  | mA         |
| dV/dt                | $V_D=400V$ Gate Open $T_j=150$                 |     | MIN. | 500 | V/ $\mu s$ |
| (dI/dt) <sub>c</sub> | (dV/dt) <sub>c</sub> =20V/ $\mu s$ , $T_j=150$ |     | MIN. | 3   | A/ms       |
| $t_{on}$             | $I_G=40mA I_A=200mA I_R=20mA$<br>$T_j=25$      |     | TYP. | 3   | $\mu s$    |
| $t_{off}$            |  |     |      | 60  |            |

### STATIC CHARACTERISTICS

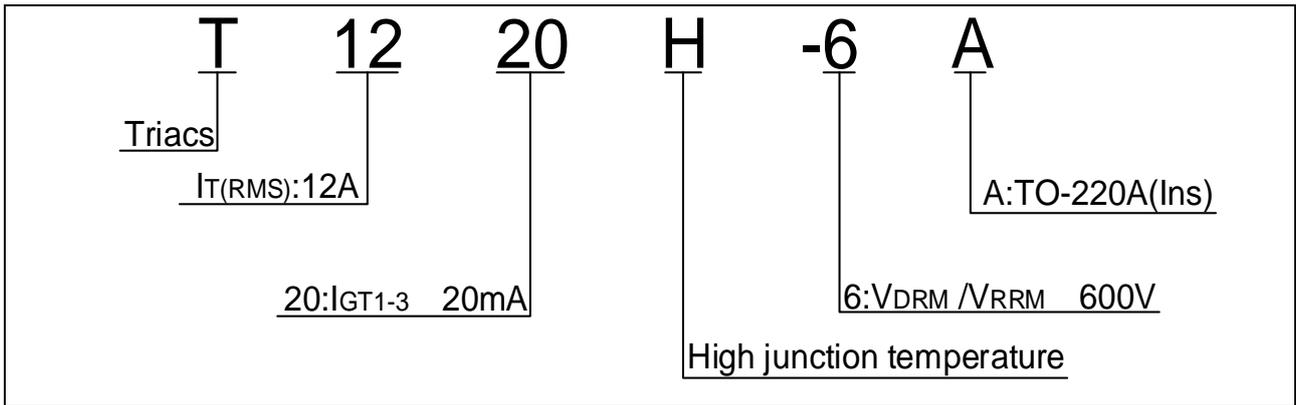
|           |                           |           |      |         |
|-----------|---------------------------|-----------|------|---------|
| $V_{TM}$  | $I_{TM}=17A t_p=380\mu s$ | $T_j=25$  | 1.4  | V       |
| $V_{TO}$  | Threshold voltage         | $T_j=150$ | 0.75 | V       |
| $R_D$     | Dynamic resistance        | $T_j=150$ | 37   | m       |
| $I_{DRM}$ | $V_D=V_{DRM} V_R=V_{RRM}$ | $T_j=25$  | 5    | $\mu A$ |
| $I_{RRM}$ |                           | $T_j=150$ | 1.5  | mA      |

### THERMAL RESISTANCES

|               |                          |     |    |
|---------------|--------------------------|-----|----|
| $R_{th(j-c)}$ | junction to case (AC)    | 2.3 | /W |
| $R_{th(j-a)}$ | junction to ambient (AC) | 60  | /W |

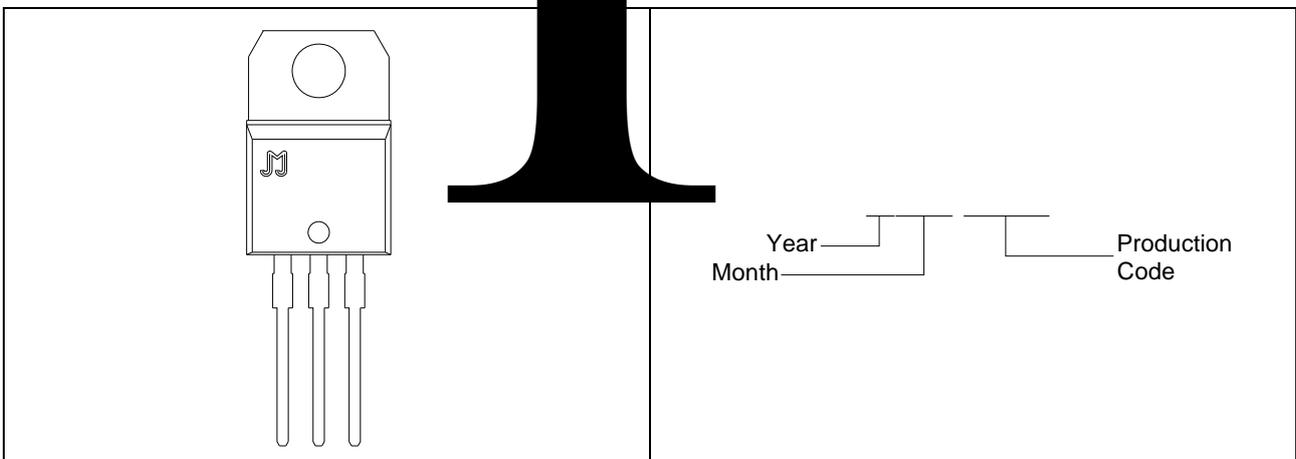


## ORDERING INFORMATION



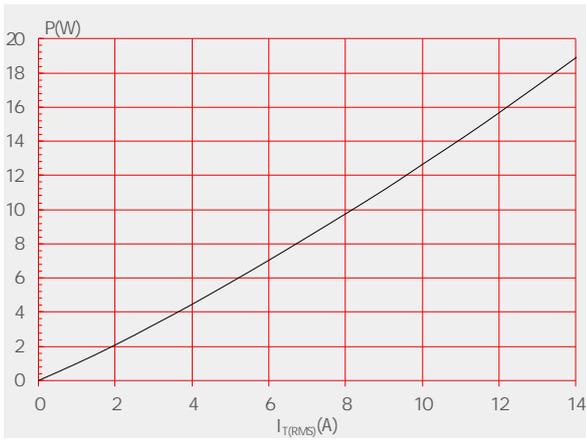
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## MARKING

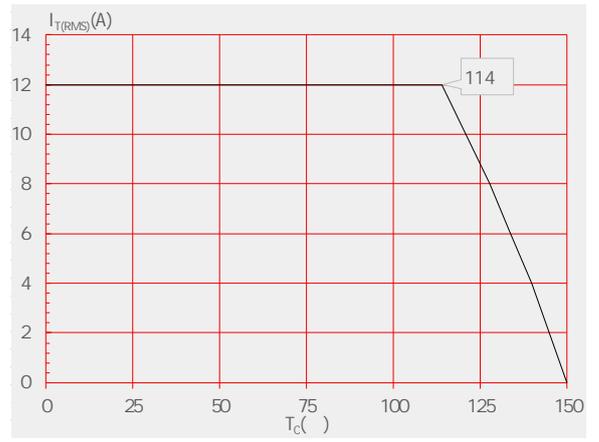




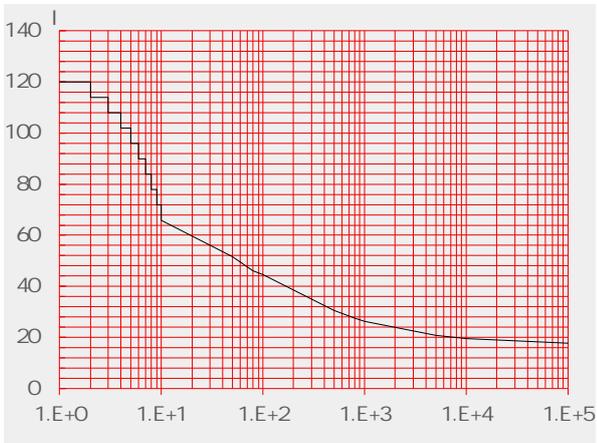
Maximum power dissipation versus RMS on-state current



RMS on-state current versus case temperature



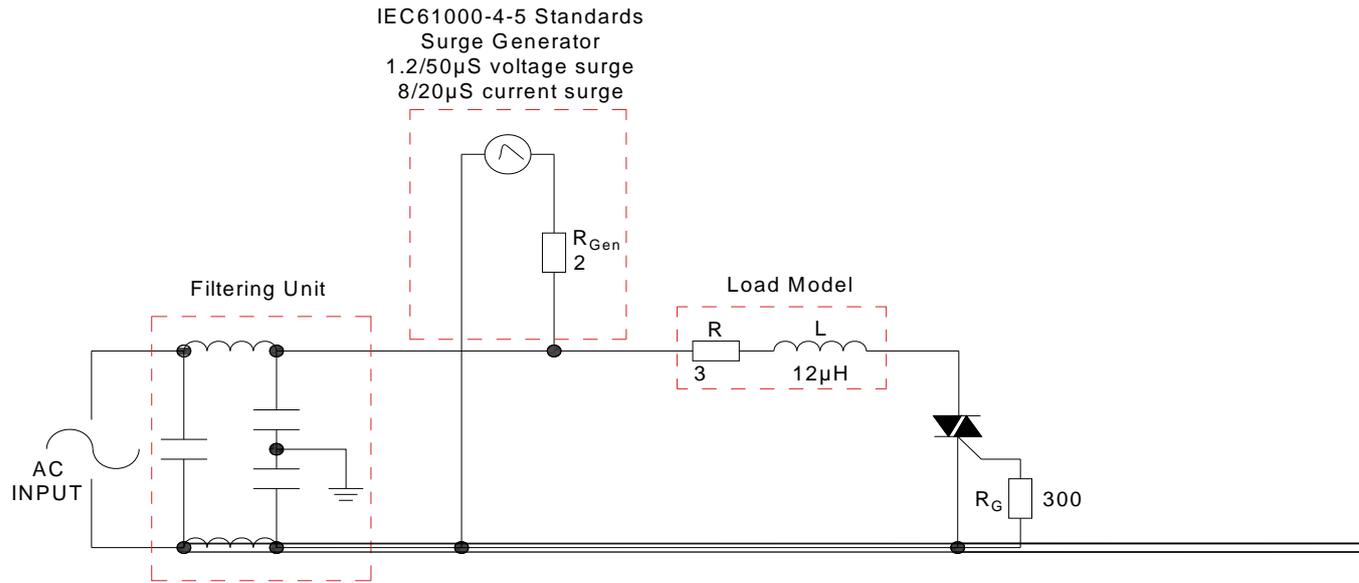
Surge peak on-state current versus number of cycles



On-state characteristic



FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



## SHAPING AND SOLDERING PARAMETERS

Refer to Instructions for installation of plastic-sealed in-line power devices released by JieJie



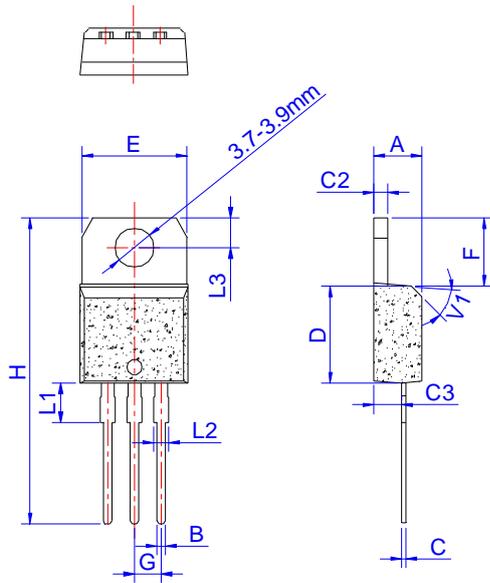
## ORDERING INFORMATION

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|  |  |  |  |  |  |
|  |  |  |  |  |  |

| Date         | Revision | Changes      |
|--------------|----------|--------------|
| Apr.11, 2023 | A.1.0    | Last updated |



## PACKAGE MECHANICAL DATA



| Ref. | Dimensions  |      |      |        |      |       |
|------|-------------|------|------|--------|------|-------|
|      | Millimeters |      |      | Inches |      |       |
|      | Min.        | Typ. | Max. | Min.   | Typ. | Max.  |
| A    | 4.40        |      | 4.60 | 0.173  |      | 0.181 |
| B    | 0.61        |      | 0.88 | 0.024  |      | 0.035 |
| C    | 0.46        |      | 0.70 | 0.018  |      | 0.028 |
| C2   | 1.21        |      | 1.32 | 0.048  |      | 0.052 |
| C3   | 2.40        |      | 2.72 | 0.094  |      | 0.107 |
| D    | 8.60        |      | 9.70 | 0.339  |      | 0.382 |
| E    | 9.80        |      | 10.4 | 0.386  |      | 0.409 |
| F    | 6.25        |      | 6.85 | 0.246  |      | 0.270 |
| G    | 2.40        |      | 2.70 | 0.094  |      | 0.106 |
| H    | 28.0        |      | 29.8 | 1.102  |      | 1.173 |
| L1   | 3.45        |      | 4.05 | 0.136  |      | 0.159 |
| L2   | 1.14        |      | 1.70 | 0.045  |      | 0.067 |
| L3   | 2.65        |      | 2.95 | 0.104  |      | 0.116 |
| V1   |             | 45°  |      |        | 45°  |       |

## DELIVERY MODE



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